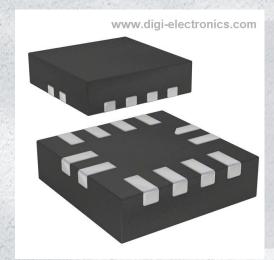


FSA2275AUMX Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number FSA2275AUMX-DG

Manufacturer onsemi

Manufacturer Product Number FSA2275AUMX

Description DPDT HIFI AUDIO SWITCH

Detailed Description Audio Switch IC 1 Channel 12-UMLP (1.8x1.8)



Tel: +00 852-30501935

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FSA2275AUMX	onsemi
Series:	Product Status:
	Active
Applications:	Multiplexer/Demultiplexer Circuit:
Audio	2:2
Switch Circuit:	Number of Channels:
DPDT	1
On-State Resistance (Max):	Voltage - Supply, Single (V+):
10hm	2.5V ~ 5.5V
Voltage - Supply, Dual (V±):	-3db Bandwidth:
	230MHz
Features:	Operating Temperature:
Break-Before-Make	-40°C ~ 80°C (TA)
Mounting Type:	Package / Case:
Surface Mount	12-UFQFN
Supplier Device Package:	Base Product Number:
12-UMLP (1.8x1.8)	FSA2275

Environmental & Export classification

8542.39.0001

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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August 2016

FSA2275 / FSA2275A — DPDT (0.5 Ω) HiFi Audio Switch w/ Negative Swing

Features

- V_{DD} Operating Range: 2.5 to 5.5 V
- External Capacitor Connection for Pop and Click Noise Suppression
- Power-Off Protection on Common Ports
- $R_{ON} = 0.5 \Omega$ (Typ.) at 2.5 V V_{DD}
- THD+N = -105 dB; 2 V_{RMS} , 20 k Ω Load; f = 1 kHz
- $X_{TALK} = -134$ dB at 1 V_{RMS} , 50 Ω Load; f = 1 kHz
- Off Isolation = -103 dB at 1 V_{RMS} , 50 Ω Load; f = 1 kHz
- 12-Lead UMLP 1.8 mm x 1.8 mm
- Removed R SHUNT resistors for FSA2275A

Applications

- Mobile Phone, Tablet, Notebook PC, Media Player
- Docking Station, TV, Set-Top Box, LCD Monitor

Description

The FSA2275 / FSA2275A is a high-performance, Double-Pole Double-Throw (DPDT) analog switch with negative swing audio capability. The FSA2275 / FSA2275A features ultra-low audio R_{ON} of $0.5\,\Omega$ (typical) at 2.5 V V $_{\text{CC}}$. The FSA2275 / FSA2275A operates over a V $_{\text{CC}}$ range of 2.5 V to 5.5 V, is fabricated with sub-micron CMOS technology to achieve fast switching speeds, and is designed for break-before-make operation. To minimize pop and click during operation, the turn on ramp time is selectable using an external capacitor (C_EXT).

The FSA2275 / FSA2275A features THD+N specifications that target a Hi-Fidelity audio quality into both 32 Ω headphones and line out type loads (>600 Ω).

The FSA2275A removes the shunt resistors which improve noise immunity.

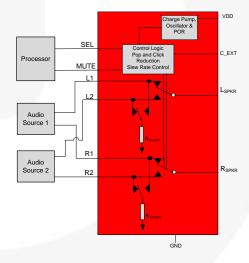


Figure 1. Application Block Diagram

Ordering Information

Part Number	Operating Temperature Range	Top Mark	Package Description	Packing Method
FSA2275UMX	40 to 95°C	NJ	12-Lead, UMLP, Quad, JEDEC MO252,	5000 Units
FSA2275AUMX -40 to 85°C		EX	1.8 mm x1.8 mm	Tape and Reel

Pin Configuration

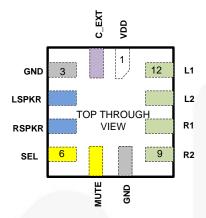


Figure 2. Pin Assignment (Top Through View)

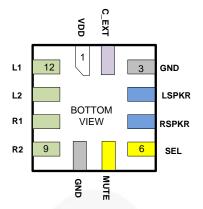


Figure 3. Pin Assignment (Bottom View)

Pin Descriptions

Pin	Name	Description			
1	VDD	Power Supply (2.5 to 5.5 V)			
2	C_EXT	Slow Turn On External Capacitor			
3	GND	Ground			
4	L _{SPKR}	Audio L _{SPPKR} Common I/O Port			
5	R _{SPKR}	Audio R _{SPPKR} Common I/O Port			
6	SEL	Select Pin			
7	MUTE	Mute Enable - Active High			
8	GND	Ground			
9	R2	Audio - Right Channel Source2 I/O Port			
10	R1	Audio – Right Channel Source1 I/O Port			
11	L2	Audio – Left Channel Source2 I/O Port			
12	L1	Audio – Left Channel Source1 I/O Port			

Truth Table

Mute	SEL	Function	Resistor Terminations
0	0	L1 = L _{SPKR} ; R1 = R _{SPKR}	R _{SHUNT(s)} connect to L2/R2 (FSA2275 only)
0	1	$L2 = L_{SPKR}$; $R2 = R_{SPKR}$	R _{SHUNT(s)} connect to L1/R1 (FSA2275 only)
1	0	L1 \neq L _{SPKR} ; L2 \neq L _{SPKR} ; R1 \neq R _{SPKR} ; R2 \neq R _{SPKR} (All Paths Hi-Z)	R _{SHUNT(s)} OPEN (FSA2275 only)
1	1	L1 ≠ L _{SPKR} ; L2 ≠ L _{SPKR} ; R1 ≠ R _{SPKR} ; R2 ≠ R _{SPKR} (All Paths Hi-Z)	R _{SHUNT(s)} OPEN (FSA2275 only)

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Paramete	Min.	Max.	Unit	
V_{DD}	Supply/Control Voltage			6.0	V
V _{CNTRL}	Control Input Voltage	SEL, MUTE	-0.3	6.0	V
V _{SW}	DC Switch I/O Voltage	Switch I/O Voltage L1, L2, R1, R2, L _{SPKR} , R _{SPKR}		3.5	V
I _{IK}	ESD Input Diode Current			-50	mA
Isw	Switch I/O Current			700	mA
	Human Body Model, ANSI/ESDA/ JEDEC JS-001-2012	All Pins	5		
ESD	Charged Device Model, JEDEC: JESD22-C	101	2		kV
	IFC 64000 4.3 System	Contact	8		
	IEC 61000-4-2 System	Air Gap	15		
T _A	Absolute Maximum Operating Temperature			+85	°C
T _{STG}	Storage Temperature			+150	°C

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Min.	Тур.	Max.	Unit
V_{DD}	Supply Voltage		2.5	3.3	5.5	V
V_{SW}	DC Switch I/O Voltage	L1, L2, R1, R2, L _{SPKR} , R _{SPKR}	-3.0		3.0	V
V _{CNTRL}	Control Input Voltage	SEL, MUTE	0	3.6	V_{DD}	V
I _{SW}	DC Switch I/O Current			100		mA
T _A	Ambient Operating Temperatu	Ambient Operating Temperature		25	+85	°C

DC Characteristics

 V_{DD} = 2.5 V to 5.5 V, V_{DD} (Typ.) = 3.3 V, T_A = -40°C to 85°C, and T_A (Typ.) = 25°C, unless otherwise specified. (1)

Symbol	Parameter	Parameter Condition		T _A =-40°C to +85°C			Unit
				Min.	Тур.	Max.	
V _{IH}	V _{CNTRL} Pin Input High Voltage (SEL, MUTE)	C_EXT = FLOAT		1.6		V _{DD}	V
V _{IL}	V _{CNTRL} Pin Input Low Voltage (SEL, MUTE)	C_EXT = FLOAT		0		0.4	V
I _{ON}	Switch-to-GND ON Leakage Current	L1, R1, L2, R2 = -3 V to 3 V, L_{SPKR} , R_{SPKR} = Float (I_{SW} = 0 mA) MUTE=LOW, SEL=0 or V_{DD} C_{EXT} = FLOAT, Figure 6	2.5 to 5.5	-1.0	0.1	1.0	μА
I _{NO_MUTE}	Switch-to-GND OFF Leakage Current (when Muted)	L1, R1, L2, R2 = -3 V to 3 V, L_{SPKR} , R_{SPKR} = Float (I_{SW} = 0 mA) MUTE = HIGH, SEL = 0 or V_{DD} C_{EXT} = FLOAT, Figure 5	2.5 to 5.5	-1.0	0.1	1.0	μА
l _{OFF}	Input Leakage Current ⁽²⁾	L1, R1, L2, R2 = -3 V to 3 V, L_{SPKR} , R_{SPKR} = Float (I_{SW} = 0 mA) MUTE = LOW, SEL = 0 or V_{DD} , C_{EXT} = FLOAT	0	-1.0	0.1	1.0	μА
I _{IN}	Control Input Leakage Current ⁽³⁾ (SEL, MUTE)	L1, R1, L2, R2 = -3 V to 3 V, L _{SPKR} , R _{SPKR} = Float (I _{SW} = 0 mA), C_EXT = FLOAT	2.5 to 5.5	-0.5	0.1	0.5	μА
I _{DD}	V _{DD} Supply Current	MUTE = LOW, SEL = 0 or V _{DD} , C_EXT = FLOAT	5.5		7	18	μА
I _{DDZ}	V _{DD} Hi-Z Supply Current	MUTE = HIGH, SEL = 0 or V _{DD} , C_EXT = FLOAT	5.5			1	μΑ
I _{DDT}	Increase in I _{DD} per Control Voltage	MUTE = LOW, SEL = 0 or 1.8 V SEL = LOW, MUTE = 0 or 1.8 V C_EXT = FLOAT	5.5			15	μA
Ron	Switch On Resistance	I _{SW} = 100 mA, V _{SW} = -3 V to 3 V C_EXT = FLOAT, Figure 4	2.5 to 5.5		0.5	1.0	Ω
ΔR _{ON}	On Resistance Matching, Channel to Channel	I _{SW} = 100 mA, V _{SW} = -3 V to 3 V C_EXT = FLOAT	2.5 to 5.5		65		mΩ
R _{FLAT}	On Resistance Flatness	I_{SW} = 100 mA, V_{SW} = -3 V to 3 V C_EXT = FLOAT	2.5 to 5.5		1	8	mΩ
R _{SHUNT}	Click and Pop Resistance (FSA2275 only) (L1, L2, R1, R2, L _{SPKR} , R _{SPKR})	V_{LX_RX} = 3.0 V, MUTE = 0, SEL = 0 or V_{DD} , C_EXT = FLOAT		6	10	14	kΩ

Notes

- 1. Limits over the recommended temperature operating range ($T_A = -40$ °C to +85°C) are correlated by statistical quality.
- 2. Only valid for $V_{SW} > 0 V$.
- 3. $V_{MUTE} \le V_{DD} + 0.3$ otherwise additional input leakage current may flow.

AC Characteristics

 V_{DD} = 2.5 V to 5.5 V, V_{DD} (Typ.) = 3.3 V. T_A = -40°C to 85°C. T_A (Typ.) = 25°C, unless otherwise specified

Cymbol	ol Parameter Condition		V _{DD}	T _A =- 40°C to +85°C			Unit	
Symbol	Parameter	Condition	l	(V)	Min.	Тур.	Max.	Unit
t _{MUTE_ON}	Enable Time (MUTE to Output)	L1 = R1 = L2 = R2 = 1.5 V, L_{SPKR} , R_{SPKR} = 50 Ω to	C_EXT=Floa	t 2.5, 3.3,		0.4		ms
	(MOTE to Output)	GND SEL= 0 or V _{DD} ; See Figure 7 and Figure 8	C_EXT=0.1 µ	F 5.5		100		
t _{ON_MUTE}	Disable Time	L1 = R1= L2 = R2 = 1.5 V, L _{SPKR} , R _{SPKR} = 50Ω to	C_EXT=Float	2.5, 3.3,		20		μs
0.00.12	(MUTE to Output)	GND, SEL = 0 or V _{DD} ; See Figure 7 and Figure 8	C_EXT=0.1 μ			20		
	Turn On Time	L1 (L2) = R1 (R2) = 1.5 V, L2 (L1) = R2 (R1) = 0 V L_{SPKR} , R_{SPKR} = 50 Ω to	C_EXT=Float	2.5,		0.4		
t _{ON_SEL}	(SEL to Output)	GND, SEL = 0 or V _{DD} ; MUTE = 0 See Figure 7 and Figure 8	C_EXT=0.1 μ	3.3, 5.5		100		ms
. 1	Turn On Time	L1 (L2) = R1 (R2) = 1.5 V, L2 (L1) = R2 (R1) = 0 V LSPKR, RSPKR = 50Ω to	C_EXT=Float	2.5,		20		
toff_sel	(SEL to Output)	GND, SEL= 0 or V _{DD} ; MUTE = 0 See Figure 7 and Figure 8	C_EXT=0.1 μ	3.3, 5.5		20		μs
t _{BBM}	Break Before Make Time (SEL to Output)	L1 (L2) = R1 (R2) = 1.5 V, L _{SPKR} , R_{SPKR} = 50 Ω to GND,SEL = 0 or V _{DD} ; C_EXT = FLOAT, MUTE = 0 V; See Figure 7 and Figure 9			N	400		μs
dV/dt_ _{PCS}	Pop n Click Suppression Output Voltage Ramp Rate	L1 = L2 = +60 mV, R1 = R2 R _{SPKR} = 50 Ω to GND, SEL = C_EXT = 0.1 μ F, MUTE = H	= 0 or V_{DD} ;	3.3		4.6		V/s
0	Off location	$ f = 1 \text{ kHz}, R_L = 50 \ \Omega, C_L = 0 \\ \text{MUTE} = 0 \ V_{\text{SW}} = 1 \ V_{\text{RMS}} \ \text{Figure} $		2.0		-103		dB
O _{IRR}	Off Isolation			3.3	A	-92		
0	Off Isolation-Muted			3.3		-108		- dB
O _{IRRM}	On isolation-inuted					-99		ub
X _{TALK}	Cross Talk (Adjacent)	$f = 1 \text{ kHz}, R_L = 50 \Omega, V_{SW} = 7$ Figure 12	1 V _{RMS}	3.3		-134		dB
BW	-3 dB Bandwidth	$R_L = 50 \Omega$ Figure 10		3.3		230		MHz
		$V_{PRSS} = V_{DD} + 100 \text{ mV}_{RMS}$	f = 217 Hz			-111		dB
PSRR	Power Supply Rejection Ratio	$R_L = 20 \text{ k}\Omega \text{ or } 32 \Omega \text{ (at } L_{SPK})$ R_{SPKR}), MUTE = 0 or V_{DD}	f = 1 kHz	3.3		-103		
	,	V _{SW} = GND or Float	f = 20 kHz			-89	A III	
		$R_L = 20 \text{ k}\Omega, f = 1 \text{ kHz}, V_{SW} =$	2 V _{RMS} with A-	3.3		0.00018		%
		weighted, Figure 15		0.0		-115		dB
THD+N	Total Harmonic	$R_L=600 \Omega$, $f=1 \text{ kHz}$, $V_{SW}=200 \Omega$	2 V _{RMS} with A-	3.3		0.00018		%
	Distortion + Noise	weighted, Figure 15				-115		dB
		$R_L = 32 \Omega$, $f = 1 \text{ kHz}$, $V_{SW} = 1 V_{RMS}$ with-A-		3.3		0.00022		%
	weighted, Figure 15				-113		dB	

Capacitance

Unless otherwise stated, V_{DD} = 2.5 V to 5.5 V, V_{DD} (Typ.) = 3.3 V, T_A = -40°C to 85°C, and T_A (Typ.) = 25°C. (4)

Symbol	Donomoton	Condition		V 00	T _A =- 40°C to +85°C			I Init
Symbol	Parameter			V _{cc} (V)	Min.	Тур.	Max.	Unit
C _{ON}	On Capacitance (Common Port)	f = 1 MHz, 100 mV _{PK-PK} , 100 mV DC bias MUTE = 0 V Figure 14		3.3		22		pF
C _{OFF1}	Off Capacitance (Common Port)	f = 1 MHz, 100 mV _{PK-PK} , 100 mV DC bias MUTE = V _{DD} Figure 13		3.3		25		pF
C _{OFF2}	Off Capacitance (Non-Common Ports)	f = 1 MHz, 100 mV _{PK-PK} , 100 mV DC bias MUTE = 0 V Figure 13		3.3		14		pF
C _{OFF_MUTE}	Off Capacitance - MUTED (Non-Common Ports)	f = 1 MHz, 100 mV _{PK-PK} , 100 mV DC bias, MUTE = V _{DD}		3.3		14		pF
C _{CNTRL}	Control Input Pin Capacitance (MUTE, SEL)	f = 1 MHz, 100 mV _{PP} , 100 mV DC bias	SEL MUTE	0		3 6		pF

Note:

4. Limits over the recommended temperature operating range (T_A=-40°C to +85°C) are correlated by statistical quality control methods.

Test Diagrams

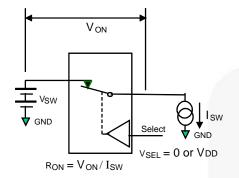


Figure 4. On Resistance

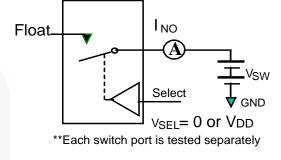


Figure 5. Off Leakage

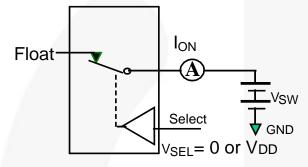


Figure 6. On Leakage

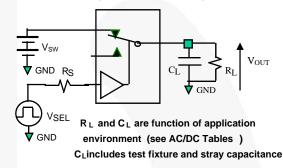


Figure 7. Test Circuit Load

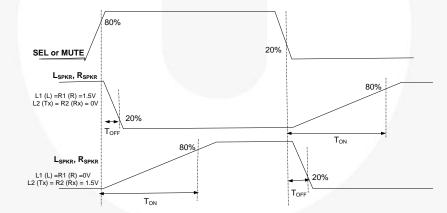


Figure 8. Turn On/Off Waveforms (SEL or MUTE to Output)

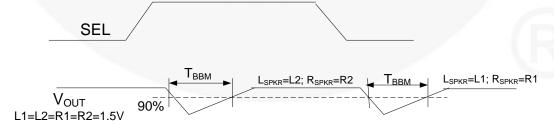


Figure 9. Break Before Make Interval Timing

Test Diagrams (Continued)

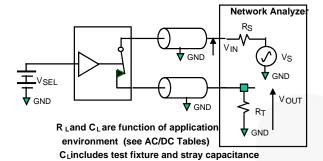


Figure 10. Bandwidth

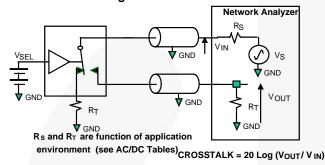


Figure 12. Adjacent Channel Crosstalk

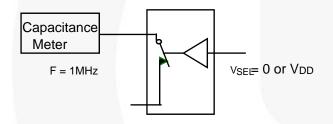


Figure 14. Channel On Capacitance

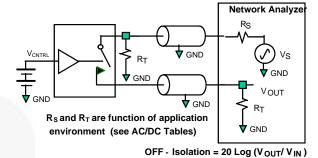


Figure 11. Channel Off Isolation

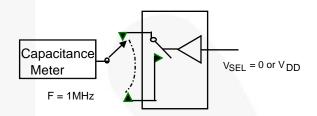


Figure 13. Channel Off Capacitance

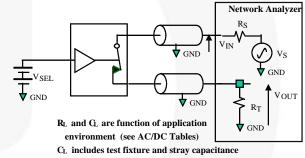
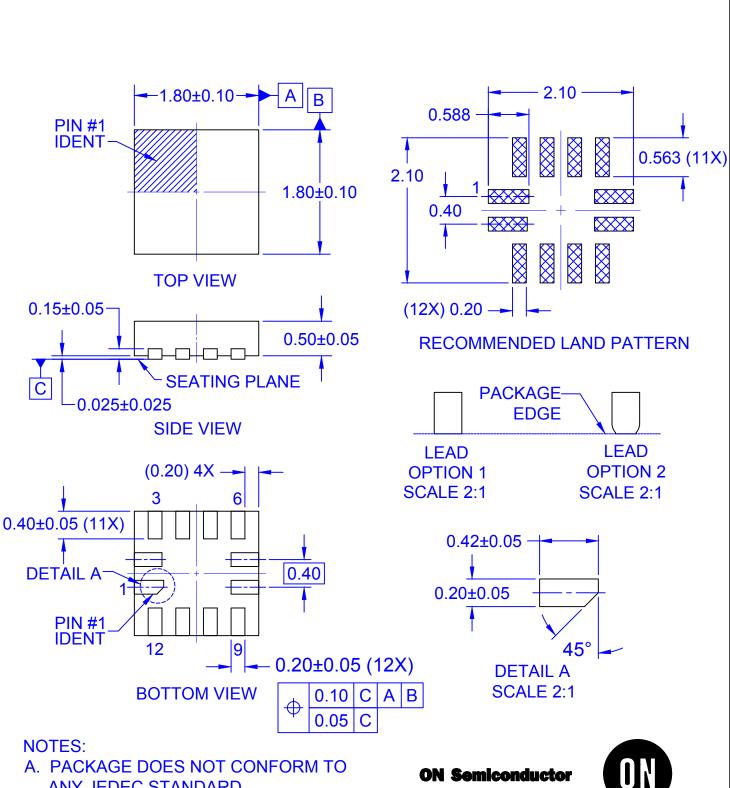


Figure 15. Total Harmonic Distortion (THD+N)



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